NSN 5962-01-407-6691



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-407-6691 **Body Length:** 32.51 millimeters **Body Width:** Between 5.59 millimeters and 7.87 millimeters **Body Height:** 4.40 millimeters **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 115.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Terminal Type And Quantity:** 24 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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